EE 330 Lecture 2

Basic Concepts



As a courtesy to fellow classmates, TAs, and the instructor

Wearing of masks during lectures and in the laboratories for this course would be appreciated irrespective of vaccination status

Grading Policy

3 Exams100 pts each1 Final100 pts.Homework100 pts.totalLab and Lab Reports100 pts.totalDesign Project100 pts.

- A letter grade will be assigned based upon the total points accumulated
- Grade breaks will be determined based upon overall performance of the class

Equal Access Policy

Participation in all class functions and provisions for special circumstances including special needs will be in accord with ISU policy

Participation in any classes or laboratories, turning in of homework, or taking any exams is optional however grades will be assigned in accord with the described grading policy. No credit will be given for any components of the course without valid excuse if students choose to not contribute. Successful completion of ALL laboratory experiments and submission of complete laboratory reports for ALL laboratory experiments to TA by deadline established by laboratory instructor is, however, required to pass this course.

Review from last lecture: How Integrated Electronics will be Approached



How Integrated Electronics will be Approached

After about four weeks, through laboratory experiments and lectures, the concepts should come together



How big is the semiconductor industry?





ABOUT - SEMIS 101 - POLICY - MARKET DATA & RESOURCES - NEWS & EVENTS -



Global Semiconductor Sales Increase 24% Year-to-Year in October; Annual Sales Projected to Increase 26% in 2021, Exceed \$600 Billion in 2022

Friday, Dec 03, 2021, 4:30pm by **Semiconductor Industry Association**

- Annual sales around \$600B in 2022
- 25% annual growth rate
- Unprecedented demand for engineers in the field

Is an automobile an electronics "gadget"?



Rewards in the Electronics Field

Can engineers working in the semiconductor electronics field make a good living?



2015 Primary Income by Primary Area of Technical Competence

	Number of Cases	Lowest Decile	Lower Quartile	Median	Upper Quartile	Highest Decile
	7,391	\$79,200	\$103,000	\$135,000	\$173,000	\$223,000
CIRCUITS AND DEVICES	1,127	\$85,000	\$110,000	\$144,700	\$182,878	\$240,000
Circuits and Systems	416	\$79,750	\$100,991	\$130,000	\$165,000	\$210,000
Components, Packaging and Manufacturing Technology	94	\$103,200	\$120,188	\$153,850	\$190,700	\$258,800
Electronic Devices	239	\$80,000	\$105,034	\$141,458	\$186,372	\$235,240
Lasers and Electro-Optics	79	\$83,800	\$112,915	¢150.000	\$184,000	\$222,800
Solid-State Circuits	277	\$105,030	\$134,000	\$165,000	\$204,700	\$265,168
Other	25	\$72,380	\$107,000	\$130,000	\$208,000	\$332,175
COMMUNICATIONS TECHNOLOGY	581	\$87,000	\$114,000	\$152,500	\$196,000	\$250,000
Broadcast Technology	46	\$64,500	\$97,500	\$141,500	\$198,000	\$326,250
Communications	419	\$87,400	\$114,945	\$153,000	\$193,28 9	\$2 46,37 0
Consumer Electronics	42	\$94,150	\$105,750	\$156,500	\$188,750	\$256,500
Vehicular Technology	21	-	-	-	-	-
Other	61	\$93,441	\$122,400	\$163,000	\$208,099	\$270,000
COMPUTERS	1,545	\$80,000	\$103,500	\$138,941	\$180,000	\$233,614
Hardware	246	\$90,000	\$110,000	\$143,702	\$182,625	\$254,261
Non-Internet Software Development	591	\$80,000	\$101,000	\$136,000	\$176,928	\$226,000
Non-Internet Systems Analysis/Integration	179	\$83,800	\$102,583	\$130,000	\$173,726	\$221,850
Non-Internet Software Applications including Database Admin.	90	\$65,260	\$100,415	\$132,500	\$165,825	\$222,500
Internet/Web Development/Applications	220	\$73,538	\$106,875	\$139,800	\$181,438	\$256,757
Other	224	\$80,300	\$108,172	\$147,500	\$181,875	\$234,290
ELECTROMAGNETICS AND RADIATION	420	\$84,900	\$110,000	\$137,912	\$169,606	\$204,655
Antennas and Propagation	103	\$78,720	\$116,100	\$140,000	\$172,000	\$197,367
Electromagnetic Compatibility	65	\$76,800	\$96,000	\$123,079	\$155,000	\$180,600
Magnetics	26	\$90,500	\$109,472	\$145,000	\$180,902	\$241,000
Microwave Theory and Techniques	114	\$79,200	\$105,314	\$133,526	\$168,344	\$200,650
Nuclear and Plasma Sciences	70	\$87,660	\$113,725	\$139,000	\$159,825	\$192,660
Other	50	\$102,000	\$121,500	\$150,000	\$184,600	\$220,000
ENERGY AND POWER ENGINEERING	1,597	\$75,000	\$94,450	\$121,000	\$152,000	\$192,000

Selected Semiconductor Trends

- Microprocessors
- DRAMS
- FPGA

Best Processors August 2021

Choose c	ategory	C	hoose min rating	Search	Search			
LAPTOP				Model name	Q			
Rank	Device	MSRP Price	3DMark Physics Score	✔ Value for Money	Popularity			
1	AMD Ryzen 9 5950X ★★★★★ DirectX 12.00	\$799	14076	17	3.5			
2	Intel Core i9-10900K Processor	\$488	13768	28	2.7			
3	Intel Core i9-10900KF Processor	\$463	13593	29	<mark>0</mark> .6			
4	Intel Core i9-10850K Processor	\$453	13440	29	1.5			
5	AMD Ryzen 9 5900X ★ ★ ★ ★ ★ DirectX 12.00	\$549	13401	24	6.6			
6	AMD Ryzen 9 3950X	\$749	13231	17	<mark>0.</mark> 9			

7	Intel Core i9-9960X Processor	n/a	13076	n/a	0.0	
8	Intel Core i9-11900K Processor ★ ★ ★ ★ ↓ ↓ DirectX 12.00	\$539	12762	23	0.3	
9	Intel Core i9-7980XE Processor ★ ★ ★ ★ DirectX 12.00	\$1979	12376	6	0.1	
10	Intel Core i9-10900 Processor ★ ★ ★ ★ DirectX 12.00	\$440	12278	27	0.1	
11	AMD Ryzen Threadripper 3960X ★ ★ ★ ★ DirectX 12.00	\$1399	12248	8	0.1	
12	AMD Ryzen 9 3900XT ★ ★ ★ ★ ★ DirectX 12.00	\$499	12124	24	0.4	
13	AMD Ryzen 9 3900X	\$499	12120	24	3.2	

Spec Breakout: Key Comparison CPUs

	AMD Ryzen 9 3900X	Intel Core i9-10900K
List Price	\$499	\$488
Cores	12	10
Threads Supported	24	20
Base Clock	3.8GHz	3.7GHz
Boost Clock	4.6GHz	5.3GHz
Integrated Graphics	None	Intel UHD 630
TDP Rating	105 watts	125 watts
Socket	AM4	LGA1200

AMD Ryzen 9 3900X (64-bit,		2040		7 & 12 nm	272 mm ²
SIMD, caches, I/O die)	9,890,000,0000,000	2019	AMD	(TSMC)	273 mm²

Intel Core i9 10900K 14nm CMOS

Recent Intel Processor



Processor

Quad-Core Intel[®] Core i7 Processor Up to 3.4GHz in 32nm CMOS Power Dissipation: 95 watts





Processor

8-core (2.6B) or 18-core Broadwell Intel[®] Core M Processor in 14nm CMOS Intel Tic-Toc product ("Toc" from 22nm Haswell processor) Power Dissipation: 4.9 watts





Processor Intel Core i9 10900K

10-core Processor in 14nm CMOS, 3.7GHz

Power Dissipation: 125 watts





Processor AMD Ryzen 5950X

16-core Processor in 7nm CMOS, 3.4-4.9 GHz

Power Dissipation: 105 watts

A bit ago!



Cannon Lake Processor

10nm CMOS i3-8121U Delayed production schedule – expected to ramp up in 2019

A bit ago!



Cannon Lake Processor

Press release from Intel – May 28, 2019

But now, <u>after years of delays</u>, the company is about to bring its first real batch* of 10nm CPUs to the world. Today, the company is officially taking the wraps off its 10th Gen Intel Core processors, codename "Ice Lake," and revealing some of what they might be able to do for your next PC when they ship in June.

Update: Intel discontinued the Cannon Lake Processor on Feb 28, 2020

Yesterday!

Processors

Processor ◆	MOS transistor count +	Date of introduction	Designer 🔶	MOS process ✦ (nm)	Area (mm²) ◆
MP944 (20-bit, 6-chip, 28 chips total)	74,442 (5,360 excl. ROM & RAM) ^{[24][25]}	1970 ^{[22][a]}	Garrett AiResearch	?	?
Intel 4004 (4-bit, 16-pin)	2,250	1971	Intel	10,000 nm	12 mm ²
TMX 1795 (?-bit, 24-pin)	3,078 ^[26]	1971	Texas Instruments	?	30 mm ²
Intel 8008 (8-bit, 18-pin)	3,500	1972	Intel	10,000 nm	14 mm ²
NEC µCOM-4 (4-bit, 42-pin)	2,500 ^{[27][28]}	1973	NEC	7,500 nm ^[29]	?
Toshiba TLCS-12 (12-bit)	11,000+ ^[30]	1973	Toshiba	6,000 nm	32 mm ²
Intel 4040 (4-bit, 16-pin)	3,000	1974	Intel	10,000 nm	12 mm ²
Motorola 6800 (8-bit, 40-pin)	4,100	1974	Motorola	6,000 nm	16 mm ²
Intel 8080 (8-bit, 40-pin)	6,000	1974	Intel	6,000 nm	20 mm ²
TMS 1000 (4-bit, 28-pin)	8,000	1974 ^[31]	Texas Instruments	8,000 nm	11 mm ²
MOS Technology 6502 (8-bit, 40-pin)	4,528 ^{[b][32]}	1975	MOS Technology	8,000 nm	21 mm ²
Intersil IM6100 (12-bit, 40-pin; clone of PDP-8)	4,000	1975	Intersil	?	?
CDP 1801 (8-bit, 2-chip, 40-pin)	5,000	1975	RCA	?	?
RCA 1802 (8-bit, 40-pin)	5,000	1976	RCA	5,000 nm	27 mm ²
Zilog Z80 (8-bit, 4-bit ALU, 40-pin)	8,500 ^[c]	1976	Zilog	4,000 nm	18 mm ²
Intel 8085 (8-bit, 40-pin)	6,500	1976	Intel	3,000 nm	20 mm ²
TMS9900 (16-bit)	8,000	1976	Texas Instruments	?	?
		1	1		



Processors

Tegra Xavier SoC (64/32-bit)	9,000,000,000 ^[127]	2018	Nvidia	12 nm	350 mm ²
AMD Ryzen 7 3700X (64-bit, SIMD, caches, I/O die)	5,990,000,000 ^{[128][d]}	2019	AMD	7 & 12 nm (TSMC)	199 (74+125) mm ²
HiSilicon Kirin 990 4G	8,000,000,000 ^[129]	2019	Huawei	7 nm	90.00 mm ²
Apple A13 (hexa-core 64-bit ARM64 "mobile SoC", SIMD, caches)	8,500,000,000 ^{[130][131]}	2019	Apple	7 nm	98.48 mm ²
AMD Ryzen 9 3900X (64-bit, SIMD, caches, I/O die)	9,890,000,000 ^{[1][2]}	2019	AMD	7 & 12 nm (TSMC)	273 mm ²
HiSilicon Kirin 990 5G	10,300,000,000 ^[132]	2019	Huawei	7 nm	113.31 mm ²
AWS Graviton2 (64-bit, 64-core ARM-based, SIMD, caches) ^{[133][134]}	30,000,000,000	2019	Amazon	7 nm	?
AMD Epyc Rome (64-bit, SIMD, caches)	39,540,000,000 ^{[1][2]}	2019	AMD	7 & 12 nm (TSMC)	1008 mm ²
TI Jacinto TDA4VM (ARM A72, DSP, SRAM)	3,500,000,000 ^[135]	2020	Texas Instruments	16 nm	
Apple A14 Bionic (hexa-core 64-bit ARM64 "mobile SoC", SIMD, caches)	11,800,000,000 ^[136]	2020	Apple	5 nm	88 mm ²
Apple M1 (octa-core 64-bit ARM64 SoC, SIMD, caches)	16,000,000,000 ^[137]	2020	Apple	5 nm	19 mm ²
HiSilicon Kirin 9000	15,300,000,000 ^{[138][139]}	2020	Huawei	5 nm	114 mm ²

FPGA Trends Today!

High-end FPGAs are quite expensive



FPGA Trends Today!

FPGA 🗢	MOS transistor count +	Date of introduction +	Designer +	Manufacturer 🗢	MOS process 🗢	Area 🗢	Ref
Virtex	70,000,000	1997	Xilinx				
Virtex-E	200,000,000	1998	Xilinx				
Virtex-II	350,000,000	2000	Xilinx		130 nm		
Virtex-II PRO	430,000,000	2002	Xilinx				
Virtex-4	1,000,000,000	2004	Xilinx		90 nm		
Virtex-5	1,100,000,000	2006	Xilinx	TSMC	65 nm		[195]
Stratix IV	2,500,000,000	2008	Altera	TSMC	40 nm		[196]
Stratix V	3,800,000,000	2011	Altera	TSMC	28 nm		[197]
Arria 10	5,300,000,000	2014	Altera	TSMC	20 nm		[198]
Virtex-7 2000T	6,800,000,000	2011	Xilinx	TSMC	28 nm		[199]
Stratix 10 SX 2800	17,000,000,000	TBD	Intel	Intel	14 nm	560 mm ²	[200][201]
Virtex-Ultrascale VU440	20,000,000,000	Q1 2015	Xilinx	TSMC	20 nm		[202][203]
Virtex-Ultrascale+ VU19P	35,000,000,000	2020	Xilinx	TSMC	16 nm	900 mm ^{2 [e]}	[204][205][206]
Versal VC1902	37,000,000,000	2H 2019	Xilinx	TSMC	7 nm		[207][208][209]
Stratix 10 GX 10M	43,300,000,000	Q4 2019	Intel	Intel	14 nm	1400 mm ^{2 [e]}	[210][211]
Versal VP1802	92,000,000,000	2021 ? ^[f]	Xilinx	TSMC	7 nm	?	[212][213]

Memory Trends

	16 Mb	SRAM (CMOS)	100,663,296	1992	Fujitsu, NEC	400 nm	2	[234]
	256 Mb	DRAM (CMOS)	268,435,456	1993	Hitachi, NEC	250 nm	f	()
	1.05	DRAM	1,073,741,824	lonuon (0, 1005	NEC	250 nm	?	[240][241]
		DRAW		January 9, 1995	Hitachi	160 nm	?	1 A 4 1 1
4 Ch	SDRAM	1,073,741,824	1996	Mitsubishi	150 nm	?	[234]	
		SDRAM (SOI)	1,073,741,824	1997	Hyundai	?	?	[242]
	DRAM (4-bit)	1,073,741,824	1997	NEC	150 nm	?	[234]	
?	4 Gb	DRAM	4,294,967,296	1998	Hyundai	?	?	[242]
	8 Gb	SDRAM (DDR3)	8,589,934,592	April 2008	Someling	50		[243]
	16 Gb	SDRAM (DDR3)	17,179,869,184	2008	Samsung	50 1111	1	
32 Gb 64 Gb	32 Gb	SDRAM (HBM2)	34,359,738,368	2016	Computer	20. pm	2	[244]
	64 Gb	SDRAM (HBM2)	68,719,476,736	2017	Samsung	20 mm	f	[= · · ·]
	128 Gb	SDRAM (DDR4)	137,438,953,472	2018	Samsung	10 nm	?	[245]

Memory Trends

?	1.06		526 970 010	2001	Samsung	?	?	[234]
	1 GD	2-bit NAND	536,870,912	2001	Toshiba, SanDisk	160 nm	?	[251]
	2 Gb	NAND	2,147,483,648	2002	Samsung, Toshiba	?	?	[252][253]
	8 Gb	NAND	8,589,934,592	2004	Samsung	60 nm	?	[252]
	16 Gb	NAND	17,179,869,184	2005 Samsung		50 nm	2	[254]
	32 Gb	NAND	34,359,738,368	2006 Samsung		40 nm	1	
THGAM	128 Gb	Stacked NAND	128,000,000,000	April 2007	Toshiba	56 nm	252 mm ²	[255]
THGBM	256 Gb	Stacked NAND	256,000,000,000	2008	Toshiba	43 nm	353 mm ²	[256]
THGBM2	1 Tb	Stacked 4-bit NAND	256,000,000,000	2010	Toshiba	32 nm	374 mm ²	[257]
KLMCG8GE4A	512 Gb	Stacked 2-bit NAND	256,000,000,000	2011	Samsung	?	192 mm ²	[258]
KLUFG8R1EM	4 Tb	Stacked 3-bit V- NAND	1,365,333,333,504	2017	Samsung	?	150 mm ²	[259]
eUFS (1 TB)	8 Tb	Stacked 4-bit V- NAND	2,048,000,000,000	2019	Samsung	?	150 mm ²	[4][260]

FPGA Trends

FPGA 🗢	MOS transistor count +	Date of introduction \$	Designer 🕈	Manufacturer 🗢	MOS process 🗢	Area 🗢	Ref
Virtex	70,000,000	1997	Xilinx				
Virtex-E	200,000,000	1998	Xilinx				
Virtex-II	350,000,000	2000	Xilinx		130 nm		
Virtex-II PRO	430,000,000	2002	Xilinx				
Virtex-4	1,000,000,000	2004	Xilinx		90 nm		
Virtex-5	1,100,000,000	2006	Xilinx	TSMC	65 nm		[195]
Stratix IV	2,500,000,000	2008	Altera	TSMC	40 nm		[196]
Stratix V	3,800,000,000	2011	Altera	TSMC	28 nm		[197]
Arria 10	5,300,000,000	2014	Altera	TSMC	20 nm		[198]
Virtex-7 2000T	6,800,000,000	2011	Xilinx	TSMC	28 nm		[199]
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Virtex-Ultrascale VU440	20,000,000,000	Q1 2015	Xilinx	TSMC	20 nm		[202][203
Virtex-Ultrascale+ VU19P	35,000,000,000	2020	Xilinx	TSMC	16 nm	900 mm ^{2 [e]}	[204][205
Versal VC1902	37,000,000,000	2H 2019	Xilinx	TSMC	7 nm		[207][208
Stratix 10 GX 10M	43,300,000,000	Q4 2019	Intel	Intel	14 nm	1400 mm ^{2 [e]}	[210][211]
Versal VP1802	92,000,000,000	2021 ? ^[f]	Xilinx	тѕмс	7 nm	?	[212][213

Special Purpose Systems

Device type 🗢	Device name ◆	Transistor count ◆	Date of introduction	Designer(s) ≑	Manufacturer(s) 🗢	MOS process	Area 🗢	Ref
Deep learning engine / IPU ^[g]	Colossus GC2	23,600,000,000	2018	Graphcore	TSMC	16 nm	~800 mm ²	[295][296][297] [better source needed]
Deep learning engine / IPU	Wafer Scale Engine	1,200,000,000,000	2019	Cerebras	TSMC	16 nm	46,225 mm ²	[5][6][7][8]
Deep learning engine / IPU	Wafer Scale Engine 2	2,600,000,000,000	2020	Cerebras	тѕмс	7 nm	46,225 mm ²	[9][298]

Selected Semiconductor Trends

- Microprocessors
 - State of the art technology is now 5 nm with over 40
 Billion transistors on a chip
- DRAMS
 - State of the art is now 128G bits on a chip in a 10nm process which requires somewhere around 140 Billion transistors
- FPGA
 - FPGAs currently have over 90 Billion transistors with 7nm technology and are growing larger
 Device count on a chip has been increasing rapidly with time, device size has been decreasing rapidly with time and speed/performance has been rapidly increasing

Moore's Law

From Webopedia (Aug 2016)

The observation made in 1965 by Gordon Moore, co-founder of <u>Intel</u>, that the number of <u>transistors</u> per square inch on <u>integrated circuits</u> had doubled every year since the integrated circuit was invented. Moore predicted that this trend would continue for the foreseeable future. In subsequent years, the pace slowed down a bit, but <u>data</u> density has doubled approximately every 18 months, and this is the current definition of Moore's Law, which Moore himself has blessed. Most experts, including Moore himself, expect Moore's Law to hold for at least another two decades.

Moore's Law: The number of transistors on microchips doubles every two years

Moore's law describes the empirical regularity that the number of transistors on integrated circuits doubles approximately every two years. This advancement is important for other aspects of technological progress in computing – such as processing speed or the price of computers.



More on Moore's Law

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S redhat.	SEE HOW WITH open technologies.	ART EXPLORING				
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Shrinking transistors have powe	Pead. NOW Wildl?	THE SCIENCES MIND HEALT	H TECH SUSTAINABILITY EDUCATION VIDEO	PODCASTS BLOGS STORE		
computing—but now other ways must be found to make computers more capable.		cinet				
by Tom Simonite May 13, 2016			TECH			
		End of Moore's Law: It's not just				

Moore's Law's End Reboots Industry | EE Times

www.eetimes.com/document.asp?doc_id=1331941 ▼

Jun 26, 2017 - The expected death of **Moore's Law** will transform the ... four years, so were reaching the **end** of semiconductor technology as we know it," said ...

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about physics

News Semiconductors Devices

Transistors Could Stop Shrinking in 2021

A key industry report forecasts an end to traditional scaling of transistors

Posted 22 Jul 2016 | 13:04 GMT By RACHEL COURTLAND

Moore's Law Running Out of Room, Tech Looks for a Successor - The ...

https://www.nytimes.com/.../moores-law-running-out-of-room-tech-looks-for-a-successo... May 4, 2016 - "The **end** of **Moore's Law** is what led to this," said Thomas M. Conte, a Georgia Institute of Technology computer scientist and co-chairman of ...

Moore's Law

From Wikopedia (Aug 2017)

....However, in April 2016, Intel CEO Brian Krzanich stated that "In my 34 years in the semiconductor industry, I have witnessed the advertised death of Moore's Law no less than four times. As we progress from 14 nanometer technology to 10 nanometer and plan for 7 nanometer and 5 nanometer and even beyond, our plans are proof that Moore's Law is alive and well".^[25] In January 2017, he declared that "I've heard the death of Moore's law more times than anything else in my career ... And I'm here today to really show you and tell you that Moore's Law is alive and flourishing."^[26]

Today hardware has to be designed in a <u>multi-core</u> manner to keep up with Moore's law. In turn, this also means that software has to be written in a <u>multi-threaded</u> manner to take full advantage of the hardware.

Moore's Law

(from Wikipedia)

Moore's law is the <u>empirical</u> observation that the <u>complexity</u> of <u>integrated</u> <u>circuits</u>, with respect to minimum component cost, doubles every 24 months[1]. It is attributed to <u>Gordon E. Moore[2]</u>, a co-founder of <u>Intel</u>.

- Observation, not a physical law
- Often misinterpreted or generalized
- Many say it has been dead for several years
- Many say it will continue for a long while
- Not intended to be a long-term prophecy about trends in the semiconductor field
- Something a reporter can always comment about when they have nothing to say!

Device scaling, device count, circuit complexity, device cost, ... in leadingedge processes will continue to dramatically improve (probably nearly geometrically with a time constant of around 2 years) for the foreseeable future !!

Field Effect Transistors



Dielectric not shown

Feature Size

The feature size of a process generally corresponds to the minimum lateral dimensions of the transistors that can be fabricated in the process



 This along with interconnect requirements and sizing requirements throughout the circuit create an area overhead factor of 10x to 100x

Challenges

- Managing increasing device count
- Short lead time from conception to marketplace
- Process technology advances
- Device performance degradation
- Increasing variability
- Increasing pressure for cost reduction
- Power dissipation

Future Trends and Opportunities

• Is there an end in sight?

No! But the direction the industry will follow is not yet known but the role semiconductor technology plays on society will increase dramatically!

• Will engineers trained in this field become obsolete at mid-career ?

No! Engineers trained in this field will naturally evolve to support the microelectronics technology of the future. Integrated Circuit designers are now being trained to efficiently manage enormous levels of complexity and any evolutionary technology will result in even larger and more complexity systems with similar and expanded skills being required by the engineering community with the major changes occurring only in the details.

Future Trends and Opportunities

 Will engineers trained in this field be doing things the same way as they are now at midcareer?

No! There have been substantive changes in approaches every few years since 1965 and those changes will continue. Continuing education to track evolutionary and revolutionary changes in the field will be essential to remain productive in the field.

 What changes can we expect to see beyond the continued geometric growth in complexity (capability) ?

That will be determined by the creativity and marketing skills of those who become immersed in the technology. New "Gordon Moores", "Bill Gates" and "Jim Dells" will evolve.

Creation of Integrated Circuits

Most integrated circuits are comprised of transistors along with a small number of passive components and maybe a few diodes

This course will focus on understanding how transistors operate and on how they can be interconnected and possibly combined with a small number of passive components to form useful integrated circuits

Texas Instruments:

- World's largest producer of analog semiconductors at \$8.2B, over 100% larger than closest competitor
- Ranks 1st in DSP
- Ranks 9th in World in semiconductor sales

Number of employees: 30,000

2018 sales: \$15.80B 2018 income: \$5.6B

(after taxes)

Average annual sales/employee: \$474K

Average annual earnings/employee: \$187K



Jerry Junkins

Past CEO of TI ISU EE Class of '59

(data from TI quarterly reports)

Intel:

World's largest producer of semiconductors

Cofounders: Robert Noyce and Gordon Moore

Number of employees (2019) : 110,000

2018 sales: \$71B

2018 income: \$21B

Average annual sales/employee: \$645K

Average annual earnings/employee: \$190K



Robert Noyce BA Grinnell 1949

Noyce is also the co-inventor of the integrated circuit !

Marvell:

Cofounders: Sehat Sutardja (CEO), Welli Dai and Pantas Sutardja

Number of employees: 5200

2018 sales: \$2.9B

2018 income: \$520M

Average annual sales/employee: \$513K

Average annual earnings/employee: \$100K

Fabless Semiconductor Company



Sehat Sutardja



Maxim: Founded in April 1983, profitable every year since 1987

Tunc Doluca joined Maxim in October 1984, appointed President and CEO in 2007

Number of employees: 7150

2018 sales: \$2.5B

2018 income: \$467M

Average annual sales/employee: \$350K

Average annual earnings/employee: \$65K



Tunc Doluca BSEE IASTATE (1979)

Wire Sizes for Electrical Interconnects



50 A Range Cord 6 ga Wiring 0.162 in diameter





25um Gold Bonding Wire



Stay Safe and Stay Healthy !

End of Lecture 2